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# Vanadium pentoxide interfacial layer enables high performance all-solid-state thin film batteries†

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Lithium cobalt oxide (LiCoO<sub>2</sub>) is considered as one of the promising building blocks that can be used to fabricate all-solid-state thin film batteries (TFBs) because of its easy accessibility, high working voltage, and high energy density. However, the slow interfacial dynamics between LiCoO<sub>2</sub> and LiPON in these TFBs results in undesirable side reactions and severe degradation of cycling and rate performance. Herein, amorphous vanadium pentoxide (V<sub>2</sub>O<sub>5</sub>) film was employed as the interfacial layer of a cathode–electrolyte solid–solid interface to fabricate all-solid-state TFBs using a magnetron sputtering method. The V<sub>2</sub>O<sub>5</sub> thin film layer assisted in the construction of an ion transport network at the cathode/electrolyte interface, thus reducing the electrochemical redox polarization potential. The V<sub>2</sub>O<sub>5</sub> interfacial layer also effectively suppressed the side reactions between LiCoO<sub>2</sub> and LiPON. In addition, the interfacial resistance of TFBs was significantly decreased by optimizing the thickness of the interfacial modification layer. Compared to TFBs without the V<sub>2</sub>O<sub>5</sub> layer, TFBs based on LiCoO<sub>2</sub>/V<sub>2</sub>O<sub>5</sub>/LiPON/Li with a 5 nm thin V<sub>2</sub>O<sub>5</sub> interface modification layer exhibited a much smaller charge transfer impedance (*R*<sub>ct</sub>) value, significantly improved discharge specific capacity, and superior cycling and rate performance. The discharge capacity remained at 75.6% of its initial value after 1000 cycles at a current density of 100 μA cm<sup>-2</sup>. This was mainly attributed to the enhanced lithium ion transport kinetics and the suppression of severe side reactions at the cathode–electrolyte interface in TFBs based on LiCoO<sub>2</sub>/V<sub>2</sub>O<sub>5</sub>/LiPON/Li with a 5 nm V<sub>2</sub>O<sub>5</sub> thin layer.

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## 1. Introduction

With the rapid development of equipment intelligence and miniaturization, there is an urgent need for energy sources that can be integrated with microdevices.<sup>1</sup> The all-solid-state lithium-ion thin film battery (TFB) has been regarded as a potential and ideal alternative due to its advantages of ultra-thin device size of several hundred micrometers (including packaging layers), excellent environmental adaptability, long cycle life, and superior storage life.<sup>1</sup> Microscale TFBs that are flexible and three-dimensional are promising candidates for the above applications because of their safety and flexible structure.<sup>1,2</sup>

A typical TFB mainly consists of current collectors, cathode, electrolyte, anode, and packaging layer.<sup>3</sup> In 1982, Hitachi Company first reported an all-solid-state TFB based on TiS<sub>2</sub>/Li<sub>3.6</sub>Si<sub>0.6</sub>P<sub>0.4</sub>O<sub>4</sub>/Li, and subsequently NTT Company fabricated a TFB based on LiCoO<sub>2</sub>/Li<sub>3.4</sub>V<sub>0.6</sub>Si<sub>0.4</sub>O<sub>4</sub>/Li.<sup>4</sup> However, the electrochemical properties of these TFBs were not satisfactory due to the limitation of the solid electrolyte. Hereafter, Bates *et al.* developed an inorganic solid electrolyte thin film by applying Li<sub>3</sub>PO<sub>4</sub> to a substrate under an N<sub>2</sub> atmosphere (LiPON) using a radio frequency (RF) magnetron sputtering approach,<sup>5</sup> which is advantageous because of its high ion conductivity (3.3 × 10<sup>-6</sup> S cm<sup>-1</sup> at 25 °C) and excellent electrochemical stability limit (>5.5 V). Due to its highly stable chemical and electrochemical properties, LiPON has been widely used to fabricate TFBs through integration with high-potential cathodes (such as LiCoO<sub>2</sub> and LiMn<sub>2</sub>O<sub>4</sub>) and thin film anodes (such as metallic lithium and SnO<sub>2</sub>).<sup>6–10</sup>

Nonetheless, there are several problems with the LiCoO<sub>2</sub>–LiPON interface in TFBs based on the LiCoO<sub>2</sub>/LiPON/Li structure. First, during the discharge process, strain at the electrode–electrolyte interface leads to a significant increase in the internal resistance of the TFBs.<sup>11</sup> Second, the annealing of LiCoO<sub>2</sub> thin films generates byproducts (Li<sub>2</sub>O, CoO, Co<sub>3</sub>O<sub>4</sub>), leading to thin film detachment and deterioration of

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electrochemical properties.<sup>12</sup> Third, there are severe side reactions between LiCoO<sub>2</sub> and LiPON during cycling, which affect the lithium-ion transport at the electrode–electrolyte interface.<sup>13,14</sup> In addition, the formation of disordered LiCoO<sub>2</sub> at the LiCoO<sub>2</sub>/LiPON interface results in lithium accumulation, which leads to further degradation of electrochemical performance.<sup>9</sup>

To reduce the interfacial strain caused by lithium ion extraction/insertion, the occurrence of side reactions must be alleviated, and the wettability and conductivity of the solid–solid interface must be increased. Thus, modification of the LiCoO<sub>2</sub>–LiPON interface is regarded as a potential method to enhance the electrochemical performance of LiCoO<sub>2</sub>/LiPON/Li TFBS.<sup>15,16</sup> It was found that a thin protective layer composed of Al<sub>2</sub>O<sub>3</sub>, MgO, or AlF<sub>3</sub> can assist in eliminating the occurrence of interfacial side reactions.<sup>17–19</sup> However, their poor mechanical and chemical stability limits their widespread applications. In such cases, the elemental interdiffusion and LiCoO<sub>2</sub>/LiPON space-charge layer between the cathode and electrolyte is effectively suppressed, thereby decreasing the interface resistance and improving the electrochemical performance of TFBS.<sup>20</sup>

For example, Hayashi *et al.* investigated lithium tungsten oxide-modified LiCoO<sub>2</sub> thin film electrodes, which apparently alleviate the hindrance of lithium ion diffusion and increase the frequency factor in LiCoO<sub>2</sub>, resulting in reduced lithium ion transfer resistance at the interface.<sup>15</sup> The introduction of intercalated pseudocapacitive interface materials for modification of the LiCoO<sub>2</sub>–LiPON interface is expected to improve its electrochemical performance.

In this work, considering the satisfactory compatibility of amorphous vanadium pentoxide (V<sub>2</sub>O<sub>5</sub>) with the LiPON interface, we propose to reduce the transfer resistance of lithium ions at the LiCoO<sub>2</sub>/LiPON interface through the construction of an interfacial nanoscale V<sub>2</sub>O<sub>5</sub> buffer layer. There are many unique advantages to amorphous vanadium oxides, such as many defects and active sites, excellent electrochemical stability, and fast ion kinetics.<sup>21,22</sup>

The magnetron sputtering method was used to construct a uniform LiCoO<sub>2</sub>/V<sub>2</sub>O<sub>5</sub>/LiPON heterointerface ion conductive network, and its modification and lithium storage mechanism were explored. The scanning electron microscopy (SEM) and energy-dispersive X-ray spectroscopy (EDS) analyses showed that a layer of V<sub>2</sub>O<sub>5</sub> was homogeneously coated on the surface of the LiCoO<sub>2</sub> cathode. Furthermore, the mechanism behind the lowered resistance with the V<sub>2</sub>O<sub>5</sub> modification layer was studied by X-ray photoelectron spectroscopy (XPS) and electrochemical techniques. The XPS analysis confirmed that V<sub>2</sub>O<sub>5</sub> interface modification can effectively inhibit undesirable interfacial side reactions. The electrochemical measurements demonstrated that the TFBS based on LiCoO<sub>2</sub>/V<sub>2</sub>O<sub>5</sub>/LiPON/Li with a 5 nm-thin V<sub>2</sub>O<sub>5</sub> interface modification layer exhibited a high discharge capacity of 34.3 μA h cm<sup>-2</sup> μm<sup>-1</sup> at a current density of 100 μA cm<sup>-2</sup> with a capacity retention of 75.6% after 1000 cycles.

## 2. Experimental section

The fabrication of LiCoO<sub>2</sub>/V<sub>2</sub>O<sub>5</sub>/LiPON/Li TFBS with an area of 1 cm<sup>2</sup> was achieved by magnetron sputtering and thermal

evaporation using the target/source materials of LiCoO<sub>2</sub>, V<sub>2</sub>O<sub>5</sub>, LiPON, and metal Li. Before magnetron sputtering and thermal evaporation deposition, a vacuum was created by evacuating the air in the chamber to 3 × 10<sup>-4</sup> Pa for the deposition of each layer. The distance between target material and substrate was set at 7 cm for all the magnetron sputtering procedures. Nine parallel samples were prepared by one magnetron sputtering treatment, which confirmed the satisfactory consistency of TFBS in this work.

### 2.1. Ti/Pt current collector deposition

The Ti/Pt current collector layer was deposited on a clean glass substrate by direct current (DC) magnetron sputtering. The Ar gas flow rate was adjusted to 100 sccm under a working pressure of 2.0 Pa. The sputtering power was set at 120 W, and the deposition time was 2 minutes. The size of the sputter target was 102.0 mm in diameter and 3 mm in thickness.

### 2.2. LiCoO<sub>2</sub> cathode deposition

The LiCoO<sub>2</sub> cathode was deposited on the top of the Ti/Pt layer by RF magnetron sputtering. The Ar and O<sub>2</sub> gas flow rates were adjusted to 80 and 20 sccm, respectively. The working pressure was 2.2 Pa, and the sputtering power was set at 954 W. The deposition time was 30 minutes. The LiCoO<sub>2</sub> layer was annealed during deposition at the temperature of 500 °C. The size of the sputter target was 152.4 mm in diameter and 3 mm in thickness.

### 2.3. V<sub>2</sub>O<sub>5</sub> interfacial layer deposition

The V<sub>2</sub>O<sub>5</sub> interfacial layer was deposited on the top of the LiCoO<sub>2</sub> cathode by RF magnetron sputtering. The Ar and O<sub>2</sub> gas flow rates were adjusted to 70 and 30 sccm, respectively. The working pressure was set at 0.3 Pa, and the sputtering power was 120 W. The deposition time was set at 2–15 minutes. The size of the sputter target was 51.0 mm in diameter and 3 mm in thickness.

### 2.4. LiPON electrolyte deposition

The LiPON layer was deposited on the top of the V<sub>2</sub>O<sub>5</sub> layer (or LiCoO<sub>2</sub> cathode layer for parallel samples) by RF magnetron sputtering. The N<sub>2</sub> gas flow rate was adjusted to 100 sccm, and the working pressure was set at 2.0 Pa. The sputtering power was set at 900 W, and the deposition time was 100 minutes.

### 2.5. Li anode deposition

The Li anode layer was deposited on the top of the LiPON layer in a thermal evaporation system equipped with a glove box. The power was adjusted to 180 W, and the deposition time was 10 minutes.

### 2.6. Morphological, structural, and electrochemical characterization

The surface morphologies of LiCoO<sub>2</sub> and the LiCoO<sub>2</sub>/V<sub>2</sub>O<sub>5</sub> thin films were examined using an SEM apparatus (S-4800, Hitachi). The EDS was acquired by coupling the SEM apparatus with an



EDS component for elemental mapping characterization. The binding energies for  $\text{LiCoO}_2/\text{V}_2\text{O}_5/\text{LiPON}$  and the  $\text{LiCoO}_2/\text{LiPON}$  thin films were determined by XPS using a PerkinElmer PHI 6000C ECSA system with monochromatic Al  $K_{\alpha}$  (1486.6 eV) irradiation after 20 s of Ar plasma etching at the etch rate of 5  $\text{nm min}^{-1}$ .

Cyclic voltammetry (CV) was carried out on a Princeton working station (AMETEK company, PMC CH808A) at a sweep rate of 0.2  $\text{mV s}^{-1}$  between 3.0 and 4.2 V. The electrochemical impedance spectra (EIS) were collected at 5 mV AC oscillation amplitude over the frequency range from 10 kHz to 0.01 Hz with an AutoLab PGSTAT302N station. Galvanostatic cycling measurements were carried out with a Land CT2001A battery test system (Wuhan LAND Electronic Co., Ltd), and the cells were cycled in the voltage range from 3.0 to 4.2 V at various current densities.

### 3. Results and discussion

#### 3.1. Morphological and structural characterization

After deposition of the  $\text{LiCoO}_2$  cathode film and  $\text{V}_2\text{O}_5$  interface layer by RF magnetron sputtering, we investigated their surface morphology and elemental distribution. Fig. 1 shows top-view SEM images of  $\text{LiCoO}_2$  and the  $\text{V}_2\text{O}_5$  layers of the  $\text{LiCoO}_2/\text{V}_2\text{O}_5/\text{LiPON}/\text{Li}$  all-solid-state TFBS. In Fig. 1a, the surface of the  $\text{LiCoO}_2$  cathode is uniform, and the film is composed of small particles 20–50 nm in size. Fig. 1b demonstrates that the  $\text{V}_2\text{O}_5$

interface modification layer is uniform and dense. The EDS mapping of the  $\text{LiCoO}_2/\text{V}_2\text{O}_5$  film in Fig. 1c shows that a layer of  $\text{V}_2\text{O}_5$  was successfully coated on the surface of the  $\text{LiCoO}_2$  cathode.

We followed the variation of the elemental composition of the films with and without the  $\text{V}_2\text{O}_5$  interface layer by high-resolution XPS surface analysis. To obtain the interfacial information between the LiPON electrolyte and  $\text{LiCoO}_2$  cathode in  $\text{LiCoO}_2/\text{V}_2\text{O}_5/\text{LiPON}$  and  $\text{LiCoO}_2/\text{LiPON}$  films, the LiPON electrolyte was deposited for 10 s, and subsequently used for XPS testing. The binding energies obtained from the XPS analysis were calibrated by referencing the C 1s peak to 284.8 eV. As shown in Fig. 2, the XPS spectra of Li 1s, N 1s, O 1s, and V 2p were obtained in small energy regions around the expected peak positions of each element after layer-by-layer etching of the as-prepared films. Fig. 2a and e show the XPS spectra of Li 1s. The peak at the binding energy of 55.1 eV originated from the Li 1s in  $\text{LiCoO}_2$ . The peak appearing at the binding energy of 56.1 eV was attributed to the Li in LiPON. In addition, there was an additional peak at the binding energy of approximately 54.1 eV, as shown in Fig. 2e, which was attributed to the Li from  $\text{Li}_2\text{O}$ .<sup>23</sup>

For the XPS spectra of N 1s in Fig. 2b and f, the binding energies of 400.1 and 398.4 eV were attributed to the double coordinated nitrogen ( $\text{N}_d$ ) and triple coordinated nitrogen ( $\text{N}_t$ ) in LiPON, respectively.<sup>24</sup> However, the intensity ratio of  $\text{N}_d/\text{N}_t$  in the  $\text{LiCoO}_2/\text{V}_2\text{O}_5/\text{LiPON}$  film was weaker compared to that in

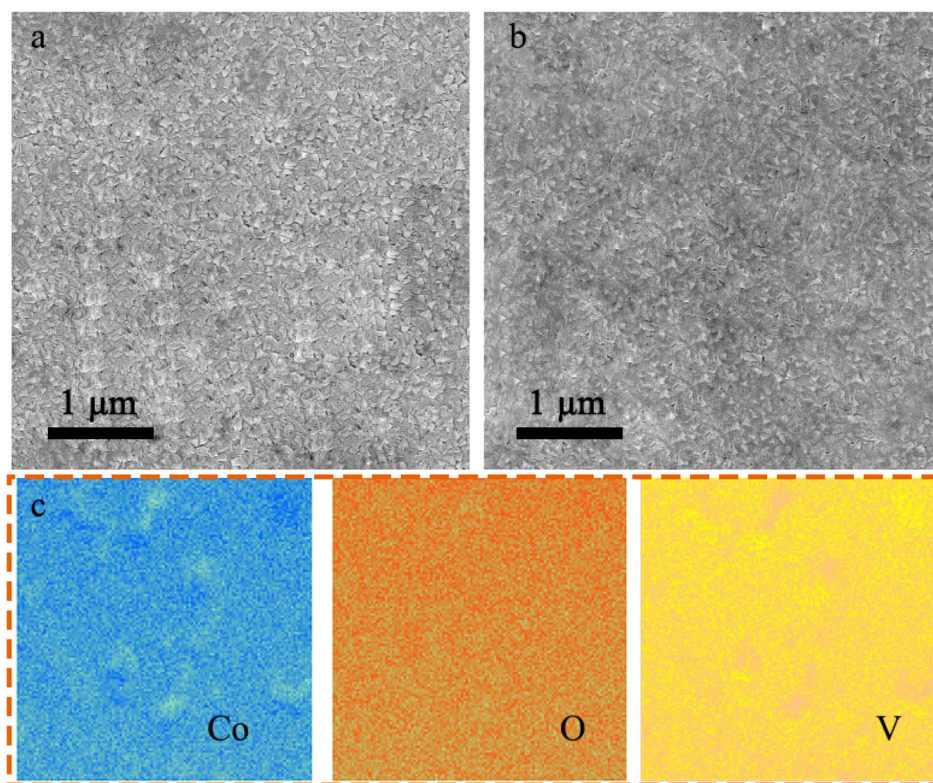


Fig. 1 Representative top-view SEM images for the surface morphology of the as-prepared (a)  $\text{LiCoO}_2$  cathode film and (b)  $\text{LiCoO}_2/\text{V}_2\text{O}_5$  film. (c) The corresponding EDS 2D mapping for element distributions of Co (blue), O (orange), and V (yellow) in the image of (b) the  $\text{LiCoO}_2/\text{V}_2\text{O}_5$  film.



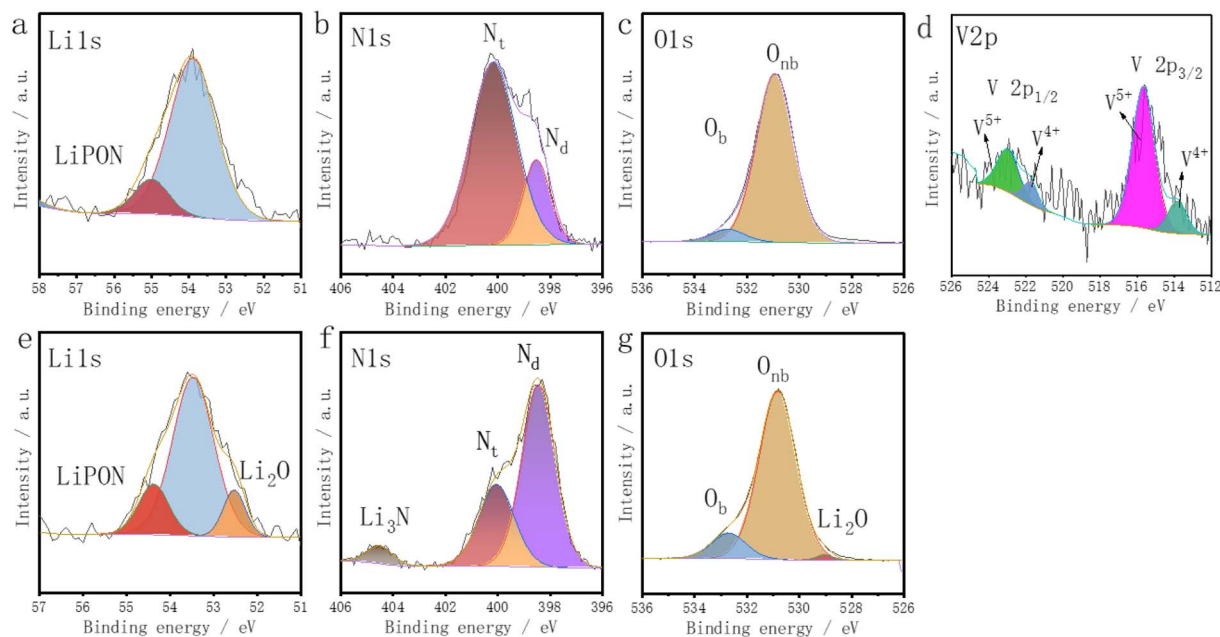


Fig. 2 High-resolution XPS spectra for elemental (a) Li 1s, (b) N 1s, (c) O 1s, and (d) V 2p of the  $\text{LiCoO}_2/\text{V}_2\text{O}_5/\text{LiPON}$  film, and (e) Li 1s (f) N 1s, and (g) O 1s of the  $\text{LiCoO}_2/\text{LiPON}$  film.

the  $\text{LiCoO}_2/\text{LiPON}$  film due to the formation of a nitrogen–vanadium triple bond in the former. In Fig. 2f, an additional peak at the binding energy of 404.6 eV appears, which originated from N in  $\text{Li}_3\text{N}$ .<sup>25</sup> The XPS spectra of O 1s in Fig. 2c and g show that the binding energies of 533.2 and 531.2 eV were attributed to bridging oxygen ( $\text{O}_b$ ) and non-bridging oxygen ( $\text{O}_{nb}$ ) in LiPON, respectively. An additional peak in Fig. 2g appears at the binding energy of 529.2 eV, which is the signal of O from  $\text{Li}_2\text{O}$ .<sup>26</sup>

Fig. 2d shows the characteristic spectrum of V 2p, which implies the presence of V only in the  $\text{LiCoO}_2/\text{V}_2\text{O}_5/\text{LiPON}$  film. The de-convoluted XPS spectra of V 2p are given in Fig. 2d, which provides a quantitative idea regarding the valence state of vanadium. The peaks located at 515.7 and 523.0 eV correspond to the  $\text{V}^{5+} 2p_{3/2}$  and  $\text{V}^{5+} 2p_{1/2}$  doublet, respectively. Nevertheless, the peaks corresponding to  $\text{V}^{4+} 2p_{3/2}$  and  $\text{V}^{4+} 2p_{1/2}$  were also observed at 513.8 and 521.7 eV, respectively. It is worth mentioning that the coexistence of the +4 and +5 oxidation states was significant for increased stability and electronic conductivity, which are crucial for electrochemical application.<sup>27,28</sup> However, in the spectrum of  $\text{LiCoO}_2/\text{LiPON}$ , there are no such peaks occurring in same binding energy range.<sup>27</sup>

Fig. S1a† shows the P 2p spectrum of LiPON, which can be resolved into the  $2p_{1/2}$  (131.9 eV),  $2p_{3/2}$  (131.1 eV), and reduced phosphorous (133.0 eV) peaks.<sup>29</sup> The former two peaks were attributed to the phosphorus bonding in  $\text{PN}_x\text{O}_{4-x}$  tetrahedrons.<sup>29</sup> Fig. S1b† shows the Co 2p spectrum of  $\text{LiCoO}_2$ , which can be resolved into the  $2p_{1/2}$  peak (794.4 eV),  $2p_{3/2}$  satellite peak (782.6 eV), and  $2p_{3/2}$  peak (788.8 eV).<sup>11</sup> The XPS analysis show that at the interface of  $\text{LiCoO}_2/\text{LiPON}$  without  $\text{V}_2\text{O}_5$  interface modification, severe side reactions lead to the generation of intermediate and secondary phases, such as  $\text{Li}_2\text{O}$  and

$\text{Li}_3\text{N}$  at the interface. XPS analysis confirmed the elemental composition and interface discrepancy in TFBS with or without a  $\text{V}_2\text{O}_5$  interface layer, which is consistent with the EDS results. These results demonstrate that  $\text{V}_2\text{O}_5$  interface modification can effectively inhibit undesirable interface reactions.

### 3.2. Electrochemical performance

To investigate the effect of thickness of the  $\text{V}_2\text{O}_5$  interface modification layer on the electrochemical performance of TFBS, CV tests were conducted on  $\text{LiCoO}_2/\text{V}_2\text{O}_5/\text{LiPON}/\text{Li}$  TFBS with different thicknesses of the  $\text{V}_2\text{O}_5$  interface layer in the voltage range of 3.0–4.2 V at a scan rate of  $0.2 \text{ mV s}^{-1}$ . Fig. 3 shows the CV curves of TFBS based on the  $\text{LiCoO}_2/\text{LiPON}/\text{Li}$  and  $\text{LiCoO}_2/\text{V}_2\text{O}_5/\text{LiPON}/\text{Li}$  structure with different thicknesses of  $\text{V}_2\text{O}_5$  film, from 2 to 15 nm. The trace trends of CV curves for all the TFBS are similar. The anodic peak occurs in the potential range of 3.9–4.0 V, and the cathodic peak occurs in the potential range of 3.8–3.9 V.

The redox peaks represent two potential stages in the extraction/insertion process of lithium ion transformation in the  $\text{LiCoO}_2$  structural sites. The redox peaks of  $\text{V}_2\text{O}_5$  are located at approximately (3.28 V, 3.12 V) and (3.47 V, 3.34 V).<sup>30</sup> The CV curves in Fig. 3b–e show that there are no significant redox peaks from  $\text{V}_2\text{O}_5$  due to the thin  $\text{V}_2\text{O}_5$  layer of 2–15 nm, which is much less than that of  $\text{LiCoO}_2$  layer. The potential differences between the anodic and cathodic peaks are approximately 43, 40, 80, and 159 mV for TFBS based on  $\text{LiCoO}_2/\text{V}_2\text{O}_5/\text{LiPON}/\text{Li}$  with different thicknesses of  $\text{V}_2\text{O}_5$  film of 2, 5, 10, and 15 nm, respectively. These results show that the smallest polarization was measured for TFBS with a 5 nm  $\text{V}_2\text{O}_5$  layer, as compared to the polarization of TFBS with other thicknesses of interface-modified layers or without a  $\text{V}_2\text{O}_5$  layer.



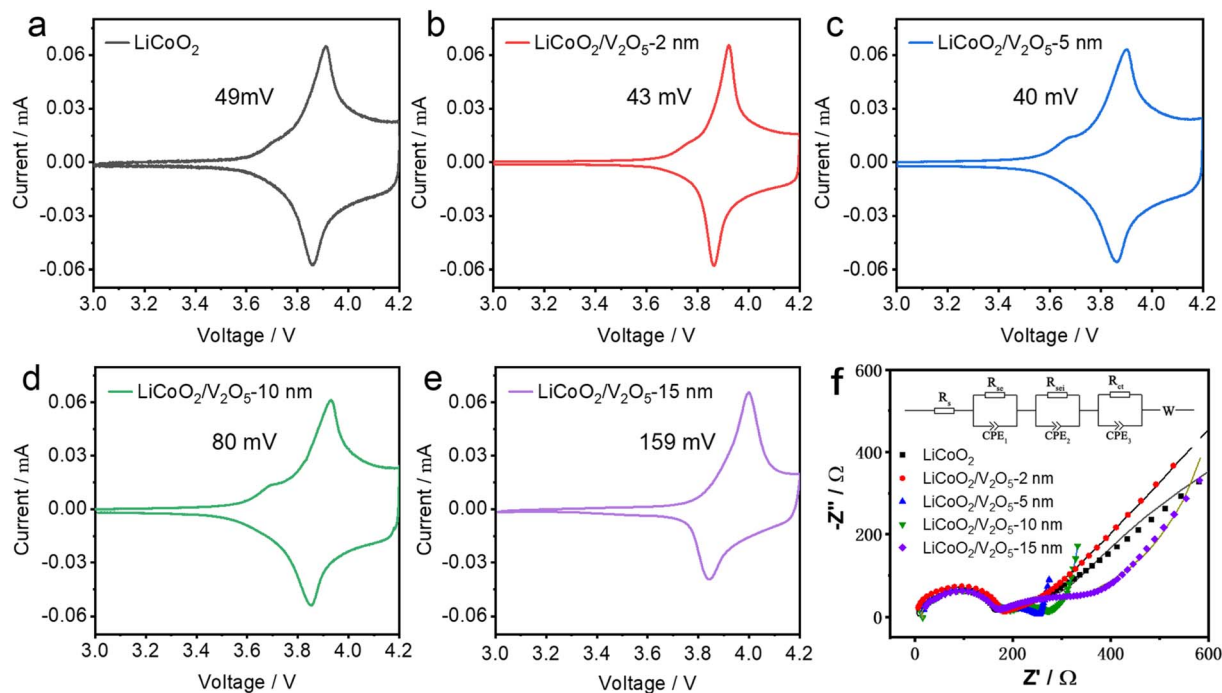


Fig. 3 Cyclic voltammetry of TFBS (a) without  $V_2O_5$  film or with (b) 2 nm-, (c) 5 nm-, (d) 10 nm-, and (e) 15 nm-thick  $V_2O_5$  film at a scan rate of  $0.2 \text{ mV s}^{-1}$  in the potential range of 3.0–4.2 V versus metallic Li. (f) Nyquist plots of impedance spectra for TFBS based on  $\text{LiCoO}_2/\text{LiPON}/\text{Li}$  or  $\text{LiCoO}_2/\text{V}_2\text{O}_5/\text{LiPON}/\text{Li}$  with different thicknesses of  $V_2O_5$  film at 2, 5, 10, and 15 nm. The fitted results are shown as the solid lines. The inset shows the equivalent circuit used for the analysis of the impedance spectra.

The larger polarization in TFBS based on the  $\text{LiCoO}_2/\text{LiPON}/\text{Li}$  structure suggests poor reversibility of cycle performance, which could be attributed to the trigger of unrecoverable side reactions between  $\text{LiCoO}_2$  and the  $\text{LiPON}$  layers. The larger polarization in TFBS based on the  $\text{LiCoO}_2/\text{V}_2\text{O}_5/\text{LiPON}/\text{Li}$  structure with only a 2 nm thickness for  $V_2O_5$  may be attributed to insufficient inhibition of side reactions. The larger polarization in TFBS based on the  $\text{LiCoO}_2/\text{V}_2\text{O}_5/\text{LiPON}/\text{Li}$  structure with a greater  $V_2O_5$  thickness (10 and 15 nm) could be caused by the lower electronic conductivity and ion conductivity of the thick  $V_2O_5$  modification layer, which can hinder the transfer and diffusion of electrons and ions. These results imply the significantly improved reversibility of the electrochemical lithium ion insertion and extraction process in  $\text{LiCoO}_2/\text{V}_2\text{O}_5/\text{LiPON}/\text{Li}$  with a 5 nm  $V_2O_5$  layer, which is consistent with the excellent cycling and rate performance of the 5 nm  $V_2O_5$  layer, as discussed in the following text.

To understand why there was a difference in electrochemical performance between TFBS based on  $\text{LiCoO}_2/\text{LiPON}/\text{Li}$  and  $\text{LiCoO}_2/\text{V}_2\text{O}_5/\text{LiPON}/\text{Li}$  with different thicknesses of the  $V_2O_5$  interfacial layer, EIS was employed to analyze the properties of the electrode/electrolyte interface. Fig. 3f shows the EIS spectra of the as-fabricated TFBS before and after  $V_2O_5$  interfacial modification. The initial intercept of the curve at the  $Z'$  axis in the high frequency region represents the ohmic resistance ( $R_s$ ) of the TFBS. The representative Nyquist plot consists of three semicircles and a diagonal. The semicircle in the high-frequency region represents the impedance of solid electrolyte  $\text{LiPON}$  ( $R_{se}$ ). The semicircle in the middle-frequency region represents the solid electrolyte interface (SEI) film impedance ( $R_{sei}$ ). The semicircle in the low-frequency region is associated with the charge transfer impedance ( $R_{ct}$ ) at the electrode/electrolyte interface. The diagonal in the low-frequency region was attributed to the Warburg diffusion of lithium ions ( $Z_w$ ).<sup>31,32</sup>

Table 1 Kinetic parameters of TFBS

TFB	$R_{se}$ ( $\Omega \text{ cm}^{-2}$ )	$R_{sei}$ ( $\Omega \text{ cm}^{-2}$ )	$R_{ct}$ ( $\Omega \text{ cm}^{-2}$ )
$\text{LiCoO}_2/\text{LiPON}/\text{Li}$	142.0	80.8	95.2
$\text{LiCoO}_2/\text{V}_2\text{O}_5\text{-2 nm}/\text{LiPON}/\text{Li}$	135.7	71.2	85.3
$\text{LiCoO}_2/\text{V}_2\text{O}_5\text{-5 nm}/\text{LiPON}/\text{Li}$	135.1	62.5	48.6
$\text{LiCoO}_2/\text{V}_2\text{O}_5\text{-10 nm}/\text{LiPON}/\text{Li}$	133.5	68.4	75.2
$\text{LiCoO}_2/\text{V}_2\text{O}_5\text{-15 nm}/\text{LiPON}/\text{Li}$	140.9	92.1	163.4



The measured EIS spectra were fitted using an equivalent circuit, as shown in the inset of Fig. 3f, and the fitting results are reported in Table 1.

Table 1 shows that the  $R_{se}$  remained similar for all the TFBS, while the  $R_{ct}$  and  $R_{sei}$  values initially decreased and then increased with the thickness of the  $V_2O_5$  interfacial modification layer. Table 1 shows that the TFBS based on the  $LiCoO_2/V_2O_5$ -5 nm/ $LiPON/Li$  structure exhibited a small  $R_{ct}$  value of  $48.6 \Omega \text{ cm}^{-2}$ , which was much less than the value for TFBS without the  $V_2O_5$  layer ( $95.2 \Omega \text{ cm}^{-2}$ ). This result indicates that the lithium ion diffusion kinetics is enhanced at the electrolyte/electrode interface for TFBS based on the  $LiCoO_2/V_2O_5$ -5 nm/ $LiPON/Li$  structure as compared to TFBS without  $V_2O_5$  layer. However, the TFBS based on the  $LiCoO_2/V_2O_5$ -15 nm/ $LiPON/Li$  structure demonstrate a  $R_{ct}$  value of  $163.4 \Omega \text{ cm}^{-2}$ , which is approximately 3.4 times larger than the value of TFBS based on the  $LiCoO_2/V_2O_5$ -5 nm/ $LiPON/Li$  structure.

The  $V_2O_5$  interfacial layer can prevent the direct contact of electrode and electrolyte, which suppresses the side reactions between the  $LiCoO_2$  and  $LiPON$  layers. The effect may be due to the decomposition products of the SEI, which was also confirmed by XPS measurement in Fig. 2. As a result, the  $V_2O_5$  thin film can enhance the diffusion kinetics of lithium ions and reduce the interface resistance. However, if the thickness of the

modification layer is too great, electron and ion transfer and diffusion will be inhibited. This results in an increase in the interface resistance when the thickness of the  $V_2O_5$  layer is greater than 5 nm, which would decrease the electrochemical lithium ion storage performance with further increasing thickness of the  $V_2O_5$  layer. The EIS results imply that the electrochemical performance in TFBS based on  $LiCoO_2/V_2O_5$ -5 nm/ $LiPON/Li$  would be significantly enhanced as compared to that in TFBS without a  $V_2O_5$  layer, while a larger impedance in TFBS based on  $LiCoO_2/V_2O_5$ -15 nm/ $LiPON/Li$  would exacerbate their decay capacity.

Fig. 4a and b shows the cyclic stability and rate performance of TFBS based on the  $LiCoO_2/LiPON/Li$  structure and  $LiCoO_2/V_2O_5/LiPON/Li$  structure with different thicknesses of the  $V_2O_5$  modification layers in the potential range of 3.0–4.2 V. The discharge capacities of TFBS based on  $LiCoO_2/LiPON/Li$ ,  $LiCoO_2/V_2O_5$ -2 nm/ $LiPON/Li$ ,  $LiCoO_2/V_2O_5$ -5 nm/ $LiPON/Li$ ,  $LiCoO_2/V_2O_5$ -10 nm/ $LiPON/Li$ , and  $LiCoO_2/V_2O_5$ -15 nm/ $LiPON/Li$  can be maintained at 31.9, 33.2, 34.3, 31.8, and 30.7  $\mu\text{A h cm}^{-2} \mu\text{m}^{-1}$  after 1000 cycles, respectively. The coulombic efficiency stabilizes at more than 95% for all the samples. The average discharge capacities of TFBS based on  $LiCoO_2/V_2O_5$ -5 nm/ $LiPON/Li$  are approximately 40.5, 39.7, 39.3, 38.9, 38.6, and 39.7  $\mu\text{A h cm}^{-2} \mu\text{m}^{-1}$  at discharge current densities of 20, 40,

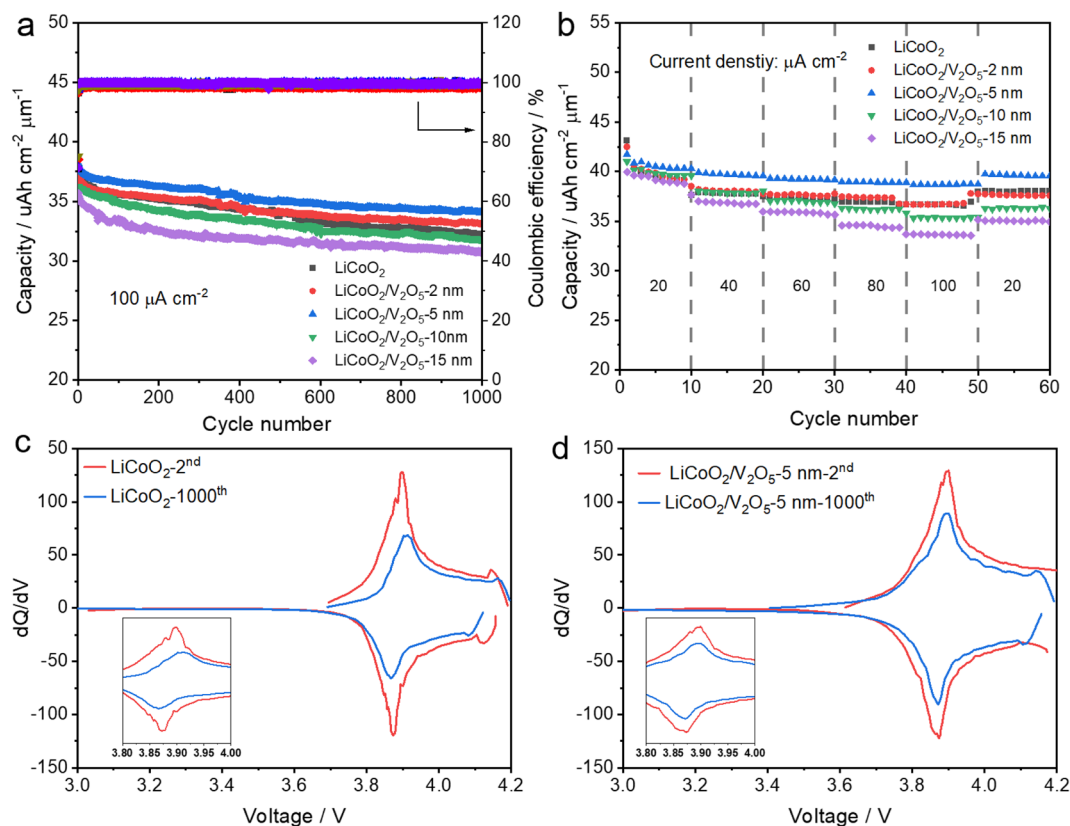


Fig. 4 Electrochemical properties for TFBS based on  $LiCoO_2/LiPON/Li$  or  $LiCoO_2/V_2O_5/LiPON/Li$  with different thicknesses of the  $V_2O_5$  modification layers. (a) Cycling behaviors and coulombic efficiency at a current density of  $100 \mu\text{A cm}^{-2}$  in the potential range of 3.0–4.2 V versus metallic Li. (b) Rate performance at different current densities of 20, 40, 60, 80, 100, and 20  $\mu\text{A cm}^{-2}$ , respectively. The differential capacity ( $dQ/dV$ ) versus voltage derived from the 2nd and 1000th charge–discharge curves of TFBS based on the (c)  $LiCoO_2/LiPON/Li$  and (d)  $LiCoO_2/V_2O_5$ -5 nm/ $LiPON/Li$  structures.



60, 80, 100, and 20  $\mu\text{A cm}^{-2}$ , respectively, showing improved values with respect to those of other samples.

The cycling and rate performance of TFBS based on the  $\text{LiCoO}_2/\text{V}_2\text{O}_5\text{-5 nm/LiPON/Li}$  structure were significantly improved with respect to the other samples. The discharge capacity remained at 75.6% of its initial value after 1000 cycles at a current density of 100  $\mu\text{A cm}^{-2}$ . The drastic degradation of cycling and rate performance in TFBS based on  $\text{LiCoO}_2/\text{LiPON/Li}$  was due to its slow interfacial dynamics between  $\text{LiCoO}_2$  and LiPON and undesirable side reactions upon cycling, which could be minimized in TFBS based on  $\text{LiCoO}_2/\text{V}_2\text{O}_5\text{-5 nm/LiPON/Li}$ . However, a thick  $\text{V}_2\text{O}_5$  modification layer (larger than 5 nm) resulted in poor performance as compared to the TFBS without the  $\text{V}_2\text{O}_5$  layer. These results are consistent with the EIS analysis discussed above.

Fig. 4c–d and S2a–c† show the differential capacity curves of  $\text{LiCoO}_2/\text{LiPON/Li}$  and  $\text{LiCoO}_2/\text{V}_2\text{O}_5\text{-5 nm/LiPON/Li}$  for the second and 1000th cycles, respectively. The redox peak at approximately 3.9 V in the  $dQ/dV$  curves was attributed to the first-order phase transition between two different hexagonal phases, which is consistent with  $\text{LiCoO}_2$ -type cathode-active materials.<sup>33</sup> The curves show that the polarization of  $\text{LiCoO}_2/\text{LiPON/Li}$  changed from 26 mV for the 2nd cycle to 45 mV for the 1000th cycle. No distinct difference in the peak positions before or after cycling was observable in TFBS based on  $\text{LiCoO}_2/\text{V}_2\text{O}_5\text{-5 nm/LiPON/Li}$ . The polarization of  $\text{LiCoO}_2/\text{V}_2\text{O}_5\text{-5 nm/LiPON/Li}$  only changed from 19 mV for the 2nd cycle to 21 mV for 1000th cycle. The polarization difference of the TFBS modified by the  $\text{V}_2\text{O}_5$  layer before and after cycling was significantly smaller than that of the TFBS without the  $\text{V}_2\text{O}_5$  layer, indicating the formation of interfaces with greater stability

between the electrode and electrolyte in TFBS based on  $\text{LiCoO}_2/\text{V}_2\text{O}_5\text{-5 nm/LiPON/Li}$ . This is consistent with the improved cycling and rate performance of TFBS based on the  $\text{LiCoO}_2/\text{V}_2\text{O}_5\text{-5 nm/LiPON/Li}$  structure.

To further elucidate the mechanism responsible for the improved electrochemical performance in TFBS with a 5 nm  $\text{V}_2\text{O}_5$  modification layer, EIS of all-solid-state TFBS based on  $\text{LiCoO}_2/\text{LiPON/Li}$  and  $\text{LiCoO}_2/\text{V}_2\text{O}_5\text{-5 nm/LiPON/Li}$  was performed for charge and discharge processes at different charge–discharge states from 0% to 100% at the interval of 10%, as shown in Fig. 5. The EIS spectra were fitted using the equivalent circuit shown in the inset of Fig. 3f to analyze the electrode/electrolyte interface properties.

Fig. 6 summarizes the fitted  $R_{\text{se}}$ ,  $R_{\text{sei}}$ , and  $R_{\text{ct}}$  values as a function of the charge–discharge state. Compared to the TFBS without  $\text{V}_2\text{O}_5$ , the  $R_{\text{se}}$ ,  $R_{\text{sei}}$ , and  $R_{\text{ct}}$  values of TFBS with a 5 nm  $\text{V}_2\text{O}_5$  modification layer decrease when the discharge state is from 100% to 0% at the first discharge process. This is mainly due to the occurrence of interfacial side reactions, the accumulation of disordered  $\text{LiCoO}_2$  growth, and the generation of rock-salt phase  $\text{CoO}$  in TFBS based on  $\text{LiCoO}_2/\text{LiPON/Li}$ , resulting in an increase in interface impedance. However, for the TFBS modified with a  $\text{V}_2\text{O}_5$  layer ( $\text{LiCoO}_2/\text{V}_2\text{O}_5\text{-5 nm/LiPON/Li}$ ), a relatively stable  $R_{\text{se}}$  was maintained during the charge process, indicating that the  $\text{V}_2\text{O}_5$  interface modification layer can inhibit the occurrence of interfacial side reactions. In addition, the  $\text{V}_2\text{O}_5$  modification layer is conducive to constructing an ion transport network at the interface between  $\text{LiCoO}_2$  and LiPON, which enhances the ion transport kinetics at the interface and further improves the electrochemical performance of TFBS based on  $\text{LiCoO}_2/\text{V}_2\text{O}_5\text{-5 nm/LiPON/Li}$ .

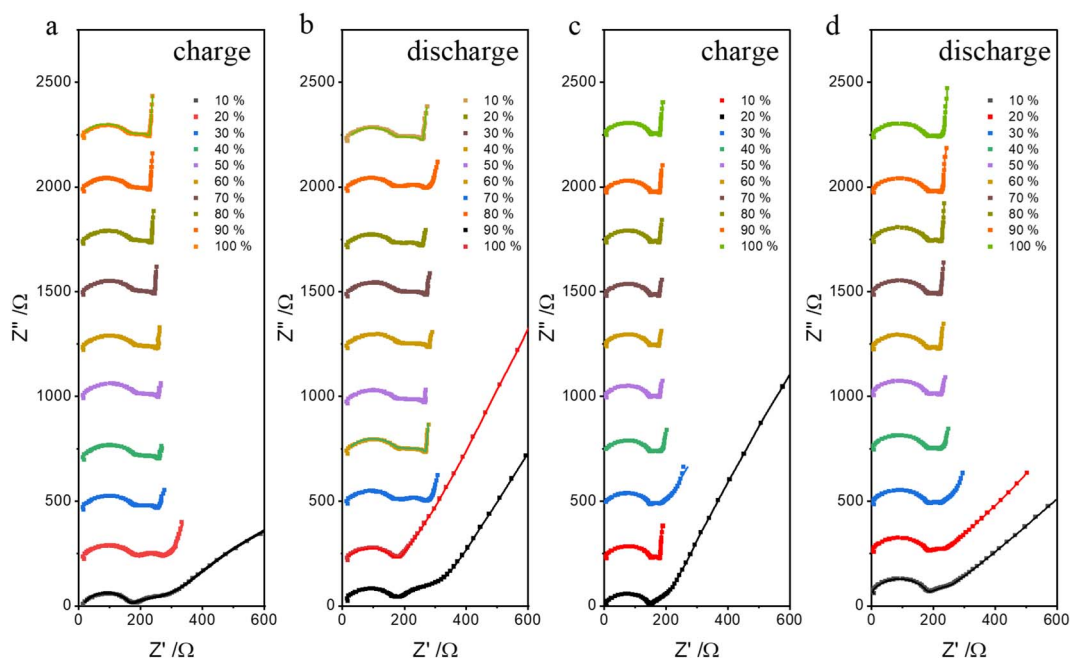


Fig. 5 Nyquist plots of impedance spectra of all-solid-state TFBS based on  $\text{LiCoO}_2/\text{LiPON/Li}$  for (a) charge and (b) discharge processes at different charge–discharge states. TFBS based on  $\text{LiCoO}_2/\text{V}_2\text{O}_5\text{-5 nm/LiPON/Li}$  for (c) charge and (d) discharge processes at different charge–discharge states from 0% to 100% at the interval of 10%. The fitted results are shown as solid lines.



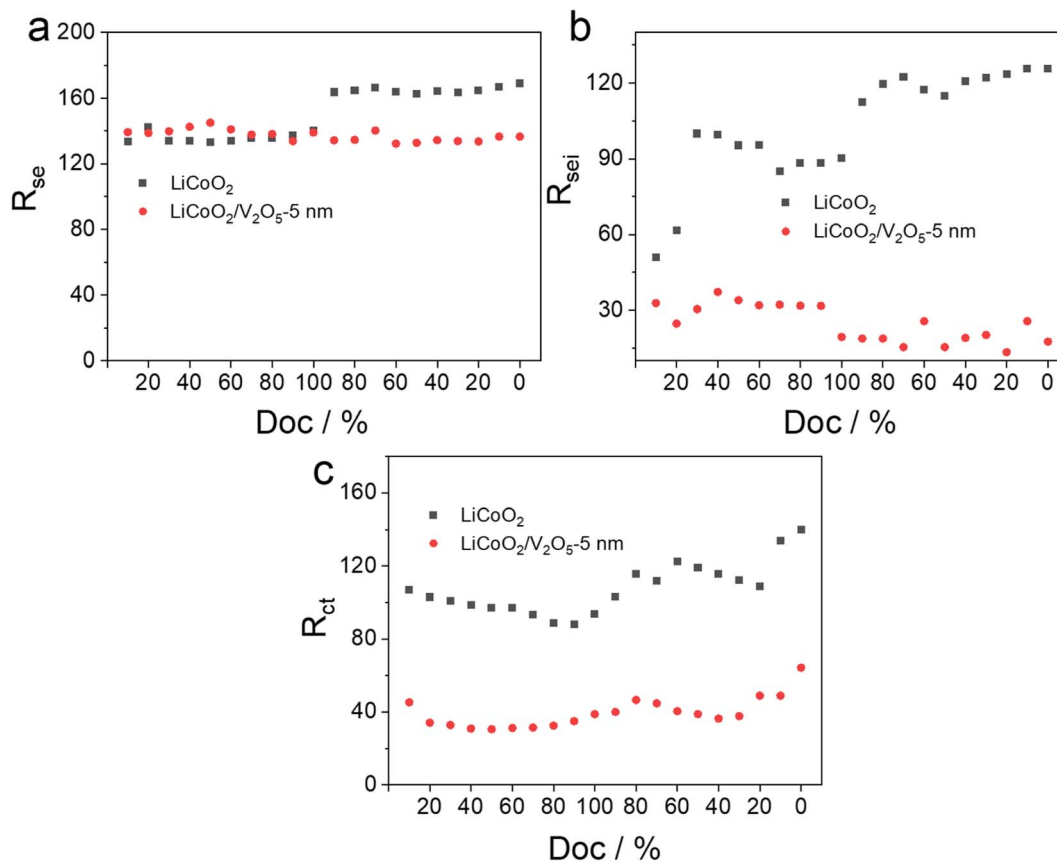


Fig. 6 The variation of impedance (a)  $R_{se}$ , (b)  $R_{sei}$ , and (c)  $R_{ct}$  with different charge–discharge states (depth of charge, doc) from 0% to 100% at the interval of 10% for all-solid-state TFBS based on  $\text{LiCoO}_2/\text{LiPON}/\text{Li}$  and  $\text{LiCoO}_2/\text{V}_2\text{O}_5\text{-5 nm}/\text{LiPON}/\text{Li}$ .

## 4. Conclusion

In this work, a  $\text{V}_2\text{O}_5$  thin film layer was introduced at the  $\text{LiCoO}_2/\text{LiPON}$  heterojunction interface to improve the interfacial transport dynamics of TFBS *via* a magnetron sputtering method. The  $\text{V}_2\text{O}_5$  thin film layer at the heterogeneous interface assisted in constructing an ion transport network, which reduced the electrochemical redox polarization potential from 49 mV to 40 mV. The  $\text{V}_2\text{O}_5$  interfacial layer effectively suppressed the side reactions between  $\text{LiCoO}_2$  and  $\text{LiPON}$ . After 1000 cycles, the electrochemical polarization potential increased by only approximately 2 mV, indicating the more stable interface between electrode and electrolyte in TFBS based on  $\text{LiCoO}_2/\text{V}_2\text{O}_5\text{-5 nm}/\text{LiPON}/\text{Li}$ .

It was found that the thickness of the  $\text{V}_2\text{O}_5$  modification layers significantly influenced the performance of  $\text{LiCoO}_2/\text{V}_2\text{O}_5/\text{LiPON}/\text{Li}$  all-solid-state TFBS. The TFBS based on  $\text{LiCoO}_2/\text{V}_2\text{O}_5/\text{LiPON}/\text{Li}$  with a 5 nm  $\text{V}_2\text{O}_5$  thin layer showed the smallest  $R_{ct}$  value of  $48.6 \Omega \text{ cm}^{-2}$ , which is only approximately half of the  $R_{ct}$  value for TFBS without the  $\text{V}_2\text{O}_5$  modification layer ( $95.2 \Omega \text{ cm}^{-2}$ ). As a result, the TFBS based on  $\text{LiCoO}_2/\text{V}_2\text{O}_5\text{-5 nm}/\text{LiPON}/\text{Li}$  exhibited a significantly increased discharge specific capacity, and superior cycling and rate performance, which was much higher than that of TFBS without the  $\text{V}_2\text{O}_5$  modification layer. The discharge capacity remained at 75.6% of its initial value after 1000 cycles at a current

density of  $100 \mu\text{A cm}^{-2}$ . This was mainly attributed to the enhanced lithium ion transport kinetics and the suppression of severe side reactions at the cathode–electrolyte interface in TFBS based on  $\text{LiCoO}_2/\text{V}_2\text{O}_5/\text{LiPON}/\text{Li}$  with a 5 nm  $\text{V}_2\text{O}_5$  thin layer, thereby achieving satisfactory electrochemical performance. This study provides an in-depth understanding of the mechanism governing electrochemical performance degradation in  $\text{LiCoO}_2/\text{LiPON}/\text{Li}$  TFBS, and also demonstrates an efficient approach to improve the electrochemical performance of TFBS through  $\text{V}_2\text{O}_5$  interface layer engineering.

## Conflicts of interest

There are no conflicts to declare.

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